NSN 5961-00-714-5135

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View Online at https://aerobasegroup.com/nsn/5961-00-714-5135 **Inclosure Material:** Metal **Overall Length:** 1.040 inches **Overall Diameter:** 0.650 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-13 **Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-emitter, base open and 15.0 breakdown voltage, emitter to collector, base open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current and 500.00 milliamperes source cutoff current **Transfer Ratio:** 20.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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